L Number	Hits		DB	Time stamp
1	23790	(SiGe (silicon near5 germanium))	USPAT;	2004/04/27 11:06
		,	US-PGPUB	
4	5758	((SiGe (silicon near5 germanium)) ) and	USPAT;	2004/04/27 11:01
		((implant\$3 dop\$4) same (SiGe (silicon near5	US-PGPUB	1
		germanium)))		
5	3377	' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' '	USPAT;	2004/04/27 10:50
		((implant\$3 dop\$4) with (SiGe (silicon near5	US-PGPUB	
		germanium)))		
6	2515	((SiGe (silicon near5 germanium)) ) and	USPAT;	2004/04/27 10:49
		((implant\$3 dop\$4) near5 (SiGe (silicon	US-PGPUB	
		near5 germanium)))		
7	5758	(((SiGe (silicon near5 germanium)) ) and	USPAT;	2004/04/27 10:49
	1	((implant\$3 dop\$4) same (SiGe (silicon near5	US-PGPUB	
		germanium))) ) (((SiGe (silicon near5		
		germanium)) ) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium))) ) (((SiGe		
		(silicon near5 germanium)) ) and ((implant\$3		
		dop\$4) near5 (SiGe (silicon near5		
		germanium))) )		
9	776	((((SiGe (silicon near5 germanium)) ) and	USPAT;	2004/04/27 11:03
		((implant\$3 dop\$4) same (SiGe (silicon near5	US-PGPUB	
		germanium))) ) (((SiGe (silicon near5		
		germanium)) ) and ((implant\$3 dop\$4) with		
1		(SiGe (silicon near5 germanium))) ) (((SiGe	1	
		(silicon near5 germanium)) ) and ((implant\$3		
		dop\$4) near5 (SiGe (silicon near5		
		germanium))) )) and ((pattern\$4 etch\$3) with		
		(SiGe (silicon near5 germanium)))		
10	1510	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	USPAT;	2004/04/27 10:51
		((implant\$3 dop\$4) same (SiGe (silicon near5	US-PGPUB	
		germanium))) ) (((SiGe (silicon near5		1
		germanium)) ) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium))) ) (((SiGe		
		(silicon near5 germanium))) and ((implant\$3		
		dop\$4) near5 (SiGe (silicon near5		
		germanium))))) and ((pattern\$4 etch\$3) same		
		(SiGe (silicon near5 germanium)))	l	1
11	191	((((SiGe (silicon near5 germanium))) and	USPAT;	2004/04/27 10:51
		((implant\$3 dop\$4) same (SiGe (silicon near5	US-PGPUB	
		germanium)))) (((SiGe (silicon near5		
]		germanium))) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium)))) (((SiGe		
		(silicon near5 germanium))) and ((implant\$3		
		dop\$4) near5 (SiGe (silicon near5	1	
		germanium))))) and ((pattern\$4 etch\$3) near		
l		(SiGe (silicon near5 germanium)))	<u> </u>	

	1 - 2222	[////6/6- /-/]		0004/04/55 50 55
12	1510	(((((SiGe (silicon near5 germanium)) ) and	USPAT;	2004/04/27 10:51
		((implant\$3 dop\$4) same (SiGe (silicon near5	US-PGPUB	
ļ		germanium))) ) (((SiGe (silicon near5	Ì	
		germanium)) ) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium))) ) (((SiGe		
		(silicon near5 germanium)) ) and ((implant\$3		
ļ		dop\$4) near5 (SiGe (silicon near5		
		germanium))) )) and ((pattern\$4 etch\$3) with		
		(SiGe (silicon near5 germanium))) )		
		(((((SiGe (silicon near5 germanium)) ) and		
1		((implant\$3 dop\$4) same (SiGe (silicon near5		
1		germanium))) ) (((SiGe (silicon near5		
		germanium)) ) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium))) ) (((SiGe		
		(silicon near5 germanium)) ) and ((implant\$3		
		dop\$4) near5 (SiGe (silicon near5		
		germanium))))) and ((pattern\$4 etch\$3) same		, i
		(SiGe (silicon near5 germanium)))))		
[		(((((SiGe (silicon near5 germanium)))) and		
		((implant\$3 dop\$4) same (SiGe (silicon near5		
1		germanium)))) (((SiGe (silicon near5		
		germanium)) ) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium))) ) (((SiGe		
		(silicon near5 germanium))) and ((implant\$3		
ł		dop\$4) near5 (SiGe (silicon near5		
		germanium))))) and ((pattern\$4 etch\$3) near		
		(SiGe (silicon near5 germanium)))))		
13	670	((((((SiGe (silicon near5 germanium)))) and	USPAT;	2004/04/27 11:04
		((implant\$3 dop\$4) same (SiGe (silicon near5	US-PGPUB	2001/01/2/ 11:01
		<pre>germanium)))) (((SiGe (silicon near5</pre>	05 10105	
•		germanium))) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium))) ) (((SiGe		
		(silicon near5 germanium))) and ((implant\$3		
		dop\$4) near5 (SiGe (silicon near5		
		germanium))))) and ((pattern\$4 etch\$3) with		
		(SiGe (silicon near5 germanium)))))		
		(((((SiGe (silicon near5 germanium)))) and		
		((implant\$3 dop\$4) same (SiGe (silicon near5		
		germanium)))) (((SiGe (silicon near5		
		germanium))) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium)))) (((SiGe		
		(silicon near5 germanium))) and ((implant\$3		
		dop\$4) near5 (SiGe (silicon near5		
		germanium))))) and ((pattern\$4 etch\$3) same		
	1	(SiGe (silicon near5 germanium)))))		
	1	(((((SiGe (silicon near5 germanium)))) and		
		((implant\$3 dop\$4) same (SiGe (silicon near5		
		germanium)))) (((SiGe (silicon near5		
		germanium))) and ((implant\$3 dop\$4) with		
		(SiGe (silicon near5 germanium)))) (((SiGe		
		(silicon near5 germanium))) and ((implant\$3		
		dop\$4) near5 (SiGe (silicon near5		
		germanium))))) and ((pattern\$4 etch\$3) near		
		(SiGe (silicon near5 germanium))))) and		
	1	TOTGE (SITICON NEGIS DELMHININI)) ) and	l	
		(bond\$3 transfer\$5)	!	

		,		
14	604	<pre>((((((((SiGe (silicon near5 germanium))) and   ((implant\$3 dop\$4) same (SiGe (silicon near5   germanium))) (((SiGe (silicon near5   germanium))) and ((implant\$3 dop\$4) with   (SiGe (silicon near5 germanium))) (((SiGe   (silicon near5 germanium))) and ((implant\$3   dop\$4) near5 (SiGe (silicon near5   germanium)))) and ((pattern\$4 etch\$3) with   (SiGe (silicon near5 germanium)))   ((((SiGe (silicon near5 germanium))) and   ((implant\$3 dop\$4) same (SiGe (silicon near5   germanium)))) (((SiGe (silicon near5   germanium)))) and ((implant\$3 dop\$4) with   (SiGe (silicon near5 germanium)))) (((SiGe   (silicon near5 germanium)))) and ((implant\$3   dop\$4) near5 (SiGe (silicon near5   germanium))))) and ((pattern\$4 etch\$3) same   (SiGe (silicon near5 germanium)))   ((((SiGe (silicon near5 germanium)))) and   (implant\$3 dop\$4) same (SiGe (silicon near5</pre>	USPAT; US-PGPUB	2004/04/27 10:52
		<pre>germanium)))) (((SiGe (silicon near5 germanium))) and ((implant\$3 dop\$4) with (SiGe (silicon near5 germanium)))) (((SiGe (silicon near5 germanium))) and ((implant\$3 dop\$4) near5 (SiGe (silicon near5 germanium))))) and ((pattern\$4 etch\$3) near (SiGe (silicon near5 germanium))))) and (bond\$3 transfer\$5)) and (insulat\$3 dielectric)</pre>		
15	32	dielectric) (((((((((siGe (silicon near5 germanium))) and ((implant\$3 dop\$4) same (SiGe (silicon near5 germanium)))) (((SiGe (silicon near5 germanium)))) (((SiGe (silicon near5 germanium)))) (((SiGe (silicon near5 germanium))))) (((SiGe (silicon near5 germanium))))) (((SiGe (silicon near5 germanium))))) and ((implant\$3 dop\$4) near5 (SiGe (silicon near5 germanium)))) ((((SiGe (silicon near5 germanium))))) ((((SiGe (silicon near5 germanium)))))) ((((SiGe (silicon near5 germanium)))))) (((SiGe (silicon near5 germanium))))) (((SiGe (silicon near5 germanium))))) (((SiGe (silicon near5 germanium)))))) and ((implant\$3 dop\$4) with (SiGe (silicon near5 germanium))))) and ((implant\$3 dop\$4) near5 (SiGe (silicon near5 germanium))))) ((((SiGe (silicon near5 germanium))))) ((((SiGe (silicon near5 germanium)))))) and ((implant\$3 dop\$4) with (SiGe (silicon near5 germanium))))) (((SiGe (silicon near5 germanium))))) (((SiGe (silicon near5 germanium))))) (((SiGe (silicon near5 germanium)))))) and ((implant\$3 dop\$4) with (SiGe (silicon near5 germanium)))))) and ((implant\$3 dop\$4) near5 (SiGe (silicon near5 germanium)))))) and ((pattern\$4 etch\$3) near (SiGe (silicon near5 germanium)))))) and (pattern\$4 etch\$3) near (SiGe (silicon near5 germanium))))))	USPAT; US-PGPUB	2004/04/27 10:53
16	8107		EPO; JPO; DERWENT; IBM TDB	2004/04/27 11:05
17	1214	((SiGe (silicon near5 germanium)) ) and (implant\$3 dop\$4)	EPO; JPO; DERWENT; IBM_TDB	2004/04/27 11:02
18	225	(((SiGe (silicon near5 germanium))) and (implant\$3 dop\$4)) and (pattern\$4 etch\$3)	EPO; JPO; DERWENT; IBM TDB	2004/04/27 11:04
19	11	((((SiGe (silicon near5 germanium)) ) and (implant\$3 dop\$4)) and (pattern\$4 etch\$3) ) and (bond\$3 transfer\$5)	EPO; JPO; DERWENT; IBM_TDB	2004/04/27 11:04
				· · · · · · · · · · · · · · · · · · ·

20	0	((SiGe (silicon near5 germanium)) ) and	EPO; JPO;	2004/04/27 11:05
		(smart near5 cut)	DERWENT;	
			IBM_TDB	
21	1	(SiGe (silicon near5 germanium)) near100	USPAT;	2004/04/27 11:08
}	}	(transfer\$4 bond\$3) near100 (etch\$3	US-PGPUB	
	1	pattern\$4) near100 (inulat\$3 dielectric)		
22	48	(SiGe (silicon near5 germanium)) same	USPAT;	2004/04/27 11:08
		(transfer\$4 bond\$3) same (etch\$3 pattern\$4)	US-PGPUB	
		same (inulat\$3 dielectric)		